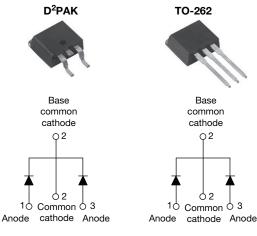
VS-32CTQ...SHM3, VS-32CTQ...-1HM3 Series

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High Performance Schottky Rectifier, 2 x 15 A



VS-32CTQ...S-M3

VS-32CTQ ... -1-M3

PRODUCT SUMMARY							
I _{F(AV)}	2 x 15 A						
V _R	25 V, 30 V						
V _F at I _F	0.40 V						
I _{RM} typ.	97 mA at 125 °C						
T _J max.	150 °C						
E _{AS}	13 mJ						
Package	TO-263AB (D ² PAK), TO-262AA						
Diode variation	Common cathode						

FEATURES

- 150 °C T_J operation
- · Low forward voltage drop
- · High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified meets JESD 201 class 1A whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-32CTQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	30	A						
V _{RRM}		25, 30	V						
I _{FSM}	t _p = 5 μs sine	900	A						
V _F	15 A _{pk} , T _J = 125 °C	0.40	V						
TJ	Range	-55 to +150	°C						

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-32CTQ025SHM3 VS-32CTQ025-1HM3	VS-32CTQ030SHM3 VS-32CTQ030-1HM3	UNITS				
Maximum DC reverse voltage	V _R	25	30	V				
Maximum working peak reverse voltage	V _{RWM}	25	50	v				

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ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS					
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T_C = 115 °C	30						
Maximum peak one cycle non-repetitive surge current	1	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	900	А				
See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	250					
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1.20 A, L = 11	13	mJ					
Repetitive avalanche current	I _{AR}	Current decaying linearly to zer Frequency limited by T _J maxim	3	А					

ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS				
		15 A	T ₁ = 25 °C	0.49					
Maximum forward voltage drop See fig. 1	V _{FM} ⁽¹⁾	30 A	1j=23 0	0.58	V				
	VFM ()	15 A	T ₁ = 125 °C	0.40	v				
		30 A	1j=125 0	0.53					
Maximum reverse leakage current	I _{BM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = rated $V_{\rm B}$	1.75	mA				
	IRM ("	T _J = 125 °C	$v_{\rm R}$ = rated $v_{\rm R}$	145					
Typical reverse leakage current	I _{RM} ⁽¹⁾	T _J = 125 °C	V_R = rated V_R	97	mA				
Threshold voltage	V _{F(TO)}	$T_{.1} = T_{.1}$ maximum		0.233	V				
Forward slope resistance	r _t	ij = ij maximum		9.09	mΩ				
Maximum junction capacitance per leg	CT	$V_R = 5 V_{DC}$ (test signal ran	1300	pF					
Typical series inductance per leg	Ls	Measured lead to lead 5 n	8.0	nH					
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs				

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to +150	°C			
Maximum thermal resistance, junction to case per leg		R _{thJC}	DC operation See fig. 4	3.25	°C/W			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50				
Approximate weight				2	g			
Approximate weight				0.07	oz.			
Mounting torque	minimum			6 (5)	kgf ⋅ cm			
Mounting torque	maximum			12 (10)	(lbf · in)			
			Case style TO 262AD (D2DAV)	32CTQ	025SH			
Marking daylige			Case style TO-263AB (D ² PAK)	32CTQ	030SH			
Marking device				32CTQ	025-1H			
			Case style TO-262AA	32CTQ	030-1H			

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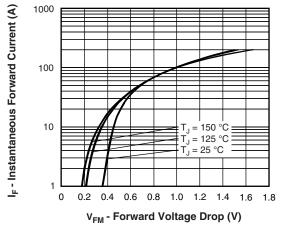
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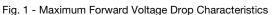
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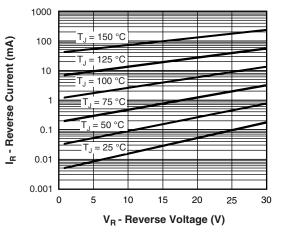


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

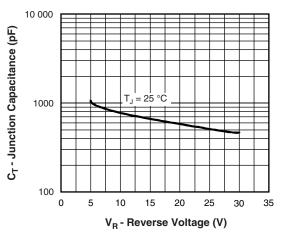
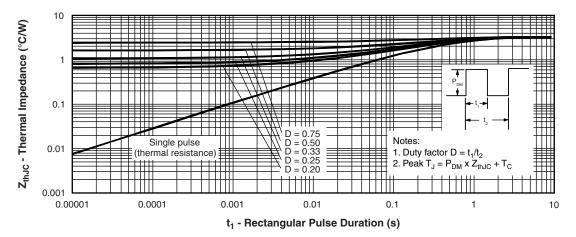


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

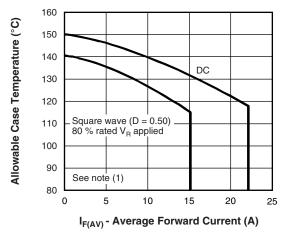


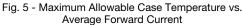


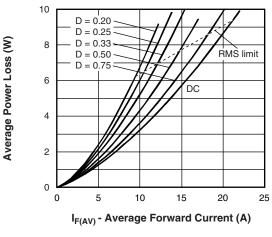


VS-32CTQ...SHM3, VS-32CTQ...-1HM3 Series

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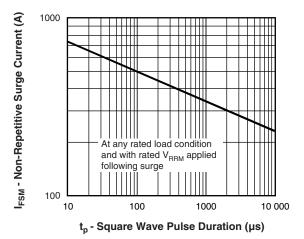


Fig. 7 - Maximum Non-Repetitive Surge Current

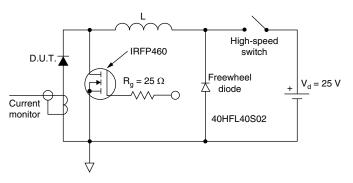


Fig. 8 - Unclamped Inductive Test Circuit

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

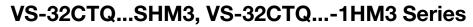
 $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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ORDERING INFORMATION TABLE

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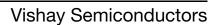
VISHAY

Device code	VS-	32	С	т	Q	030	S	TRL	н	М3	
		2	3	4	5	6	(7)	8	9	10	
	2 - 3 - 4 - 5 -	 3 - Circuit configuration: C = common cathode 4 - T = TO-220 5 - Schottky "Q" series 6 - Voltage ratings									
	8 - 9 - 10 -	• No • TF • TF H =	RR = tap AEC-Q	be e and re be and re 101 qua	eel (right Ilified	t oriente	d - for E	PAK onl) ² PAK o erminatio	nly)	(Pb)-free	

ORDERING INFORMATION										
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION							
VS-32CTQ025SHM3	50	1000	Antistatic plastic tubes							
VS-32CTQ025STRRHM3	800	800	13" diameter reel							
VS-32CTQ025STRLHM3	800	800	13" diameter reel							
VS-32CTQ025-1HM3	50	1000	Antistatic plastic tubes							
VS-32CTQ030SHM3	50	1000	Antistatic plastic tubes							
VS-32CTQ030STRRHM3	800	800	13" diameter reel							
VS-32CTQ030STRLHM3	800	800	13" diameter reel							
VS-32CTQ030-1HM3	50	1000	Antistatic plastic tubes							

LINKS TO RELATED DOCUMENTS								
Dimensions	TO-263AB (D ² PAK)	www.vishay.com/doc?95046						
Dimensions	TO-262AA	www.vishay.com/doc?95419						
Part marking information	TO-263AB (D ² PAK)	www.vishay.com/doc?95444						
Part marking information	TO-262AA	www.vishay.com/doc?95443						
Packaging information		www.vishay.com/doc?95032						

Outline Dimensions

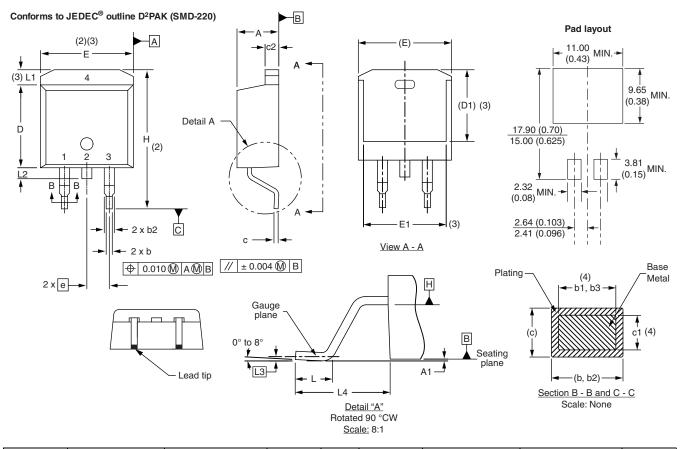


D²PAK

DIMENSIONS in millimeters and inches

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SHA



SYMBOL	MILLIM	IETERS	INC	HES	NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

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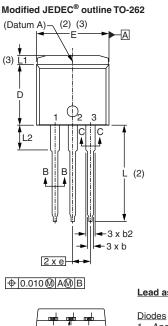
Outline Dimensions



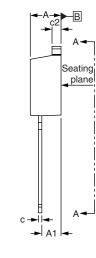
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TO-262

DIMENSIONS in millimeters and inches

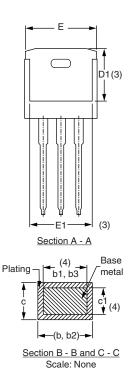


Lead tip -



Lead assignments

1. - Anode (two die)/open (one die) 2., 4. - Cathode 3. - Anode



MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. А 4.06 4.83 0.160 0.190 2.03 A1 3.02 0.080 0.119 b 0.51 0.99 0.020 0.039 b1 0.51 0.89 0.020 0.035 4 b2 1.14 1.78 0.045 0.070 1.14 1.73 0.045 0.068 4 b3 0.38 0.74 0.015 0.029 С 0.38 0.58 0.015 0.023 4 c1 1.14 1.65 0.045 0.065 c2 D 8.51 9.65 0.335 0.380 2 D1 6.86 8.00 0.270 0.315 3 Е 9.65 10.67 0.380 0.420 2, 3 E1 7.90 8.80 0.311 0.346 3 0.100 BSC 2.54 BSC е L 13.46 14.10 0.530 0.555 L1 _ 1.65 0.065 3 _ 3.36 0.132 0.146 L2 3.71

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) , D1 (minimum) and L2 where dimensions derived the actual package outline

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Document Number: 95419

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